Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Glass

**Overall Length:** 

0.185 inches

# Terminal Length:

1.300 inches

# **Overall Diameter:**

0.185 inches

# **Function For Which Designed:**

Transient suppressor

# Mounting Method:

Terminal

#### Features Provided:

Hermetically sealed case

# Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

132.0 reverse breakdown voltage, dc

# **Current Rating Per Characteristic:**

10.00 milliamperes forward current, total rms nanoamperes

# **Power Rating Per Characteristic:**

500.0 watts small-signal input power, common-collector preset

# Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

# **Test Data Document:**

18876-+19500-180 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

# Terminal Type And Quantity:

2 uninsulated wire lead

# Shelf Life:

N/a

# Unit Of Measure:

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#### Demilitarization:

No

# Fiig:

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